

# Mattias Kruskopf

## List of Publications by Year in Descending Order

**Source:** <https://exaly.com/author-pdf/8543890/mattias-kruskopf-publications-by-year.pdf>

**Version:** 2024-04-24

This document has been generated based on the publications and citations recorded by exaly.com. For the latest version of this publication list, visit the link given above.

The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

42  
papers

437  
citations

13  
h-index

19  
g-index

53  
ext. papers

633  
ext. citations

3.8  
avg, IF

3.55  
L-index

#	Paper	IF	Citations
42	A four-terminal-pair Josephson impedance bridge combined with a graphene-quantized Hall resistance. <i>Measurement Science and Technology</i> , <b>2021</b> , 32, 065007	2	3
41	Graphene Quantum Hall Effect Devices for AC and DC Electrical Metrology. <i>IEEE Transactions on Electron Devices</i> , <b>2021</b> , 68, 3672-3677	2.9	1
40	Graphene quantum Hall effect parallel resistance arrays. <i>Physical Review B</i> , <b>2021</b> , 103,	3.3	2
39	Highly sensitive broadband binary photoresponse in gateless epitaxial graphene on 4HSiC. <i>Carbon</i> , <b>2021</b> , 184, 72-81	10.4	1
38	Magnetotransport in hybrid InSe/monolayer graphene on SiC. <i>Nanotechnology</i> , <b>2021</b> , 32, 155704	3.4	1
37	Development of gateless quantum Hall checkerboard p $\bar{n}$ junction devices. <i>Journal Physics D: Applied Physics</i> , <b>2020</b> , 53, 345302	3	
36	Analysing quantized resistance behaviour in graphene Corbino junction devices. <i>Journal Physics D: Applied Physics</i> , <b>2020</b> , 53,	3	3
35	Quantum Hall resistance dartboards using graphene p-n junction devices with Corbino geometries. <i>AIP Advances</i> , <b>2020</b> , 10, 035205	1.5	3
34	Nanostructured graphene for nanoscale electron paramagnetic resonance spectroscopy. <i>JPhys Materials</i> , <b>2020</b> , 3, 014013	4.2	4
33	Accessing ratios of quantized resistances in graphene p $\bar{n}$ junction devices using multiple terminals. <i>AIP Advances</i> , <b>2020</b> , 10, 025112	1.5	3
32	Implementation of a graphene quantum Hall Kelvin bridge-on-a-chip for resistance calibrations. <i>Metrologia</i> , <b>2020</b> , 57,	2.1	2
31	Analytical determination of atypical quantized resistances in graphene junctions. <i>Physica B: Condensed Matter</i> , <b>2020</b> , 582,	2.8	1
30	A Self-Assembled Graphene Ribbon Device on SiC. <i>ACS Applied Electronic Materials</i> , <b>2020</b> , 2, 204-212	4	0
29	Analytical determination of atypical quantized resistances in graphene p-n junctions. <i>Physica B: Condensed Matter</i> , <b>2020</b> , 582, 411971	2.8	6
28	Graphene quantum Hall effect devices for AC and DC resistance metrology <b>2020</b> ,		2
27	The EMPIR Project GIQS: Graphene Impedance Quantum Standard <b>2020</b> ,		1
26	Superconducting Contact Geometries for Next-Generation Quantized Hall Resistance Standards. <i>IEEE Transactions on Instrumentation and Measurement</i> , <b>2020</b> , 1.633481E6,	5.2	1

25	AC Quantum Hall Resistance combined with a Four-Terminal Pair Pulse-Driven Josephson Impedance Bridge <b>2020</b> ,		3
24	Comparison between Graphene and GaAs Quantized Hall Devices with a Dual Probe. <i>IEEE Transactions on Instrumentation and Measurement</i> , <b>2020</b> , 69, 9374-9380	5.2	0
23	Next-generation crossover-free quantum Hall arrays with superconducting interconnections. <i>Metrologia</i> , <b>2019</b> , 56,	2.1	13
22	Atypical Quantized Resistances in Millimeter-Scale Epitaxial Graphene Junctions. <i>Carbon</i> , <b>2019</b> , 154, 230-230	10.4	10
21	Two-Terminal and Multi-Terminal Designs for Next-Generation Quantized Hall Resistance Standards: Contact Material and Geometry. <i>IEEE Transactions on Electron Devices</i> , <b>2019</b> , 66,	2.9	19
20	Gateless and reversible carrier density tunability in epitaxial graphene devices functionalized with chromium tricarbonyl. <i>Carbon</i> , <b>2019</b> , 142, 468-468	10.4	22
19	Comparison between NIST Graphene and AIST GaAs Quantized Hall Devices. <i>IEEE Transactions on Instrumentation and Measurement</i> , <b>2019</b> ,	5.2	7
18	Examining epitaxial graphene surface conductivity and quantum Hall device stability with Parylene passivation. <i>Microelectronic Engineering</i> , <b>2018</b> , 194, 51-55	2.5	12
17	Infrared Nanospectroscopy of Phospholipid and Surfactin Monolayer Domains. <i>ACS Omega</i> , <b>2018</b> , 3, 4141-4147	3.9	19
16	Minimum Resistance Anisotropy of Epitaxial Graphene on SiC. <i>ACS Applied Materials &amp; Interfaces</i> , <b>2018</b> , 10, 6039-6045	9.5	33
15	Compressed sensing FTIR nano-spectroscopy and nano-imaging. <i>Optics Express</i> , <b>2018</b> , 26, 18115-18124	3.3	14
14	Graphene Devices for Tabletop and High-Current Quantized Hall Resistance Standards. <i>IEEE Transactions on Instrumentation and Measurement</i> , <b>2018</b> , 68,	5.2	17
13	A Table-Top Graphene Quantized Hall Standard <b>2018</b> ,		3
12	Epitaxial Graphene for High-Current QHE Resistance Standards <b>2018</b> ,		1
11	Uncertainty of the Ohm Using Cryogenic and Non-Cryogenic Bridges <b>2018</b> ,		2
10	Confocal laser scanning microscopy for rapid optical characterization of graphene. <i>Communications Physics</i> , <b>2018</b> , 1,	5.4	24
9	Towards epitaxial graphene p-n junctions as electrically programmable quantum resistance standards. <i>Scientific Reports</i> , <b>2018</b> , 8, 15018	4.9	19
8	Quantum Hall device data monitoring following encapsulating polymer deposition. <i>Data in Brief</i> , <b>2018</b> , 20, 1201-1208	1.2	3

7	Epitaxial graphene for quantum resistance metrology. <i>Metrologia</i> , <b>2018</b> , 55,	2.1	23
6	A morphology study on the epitaxial growth of graphene and its buffer layer. <i>Thin Solid Films</i> , <b>2018</b> , 659, 7-15	2.2	17
5	AC Quantum Hall Effect in Epitaxial Graphene. <i>IEEE Transactions on Instrumentation and Measurement</i> , <b>2017</b> , 66, 1459-1466	5.2	7
4	Magnetocapacitance and dissipation factor of epitaxial graphene-based quantum Hall effect devices. <i>Physical Review B</i> , <b>2017</b> , 96,	3.3	5
3	Comeback of epitaxial graphene for electronics: large-area growth of bilayer-free graphene on SiC. <i>2D Materials</i> , <b>2016</b> , 3, 041002	5.9	95
2	Nonequilibrium mesoscopic conductance fluctuations as the origin of $1/f$ noise in epitaxial graphene. <i>Physical Review B</i> , <b>2016</b> , 94,	3.3	10
1	Epitaxial graphene on SiC: modification of structural and electron transport properties by substrate pretreatment. <i>Journal of Physics Condensed Matter</i> , <b>2015</b> , 27, 185303	1.8	23